

UNISONIC TECHNOLOGIES CO., LTD

14N50K-MT

Preliminary

Power MOSFET

14A, 500V N-CHANNEL POWER MOSFET

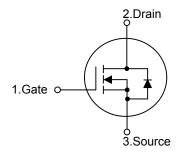
■ DESCRIPTION

The UTC **14N50K-MT** is a N-channel power MOSFET using UTC's advanced technology to provide the customers with minimum on-state resistance, superior switching performance and withstand high energy pulse in the avalanche and commutation mode.

■ FEATURES

- * $R_{DS(ON)}$ < 0.4 Ω @ V_{GS} =10V, I_{D} =7.0A
- * High Switching Speed

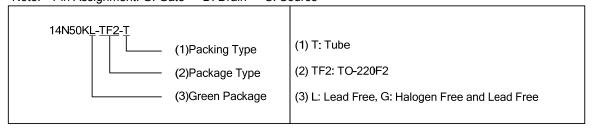




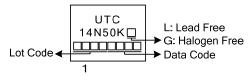
ORDERING INFORMATION

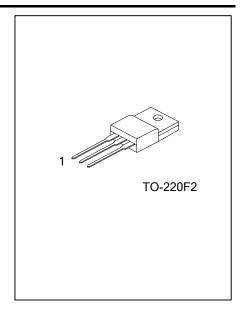
Ordering Number		Dookogo	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
14N50KL-TF2-T	14N50KG-TF2-T	TO-220F2	G	D	S	Tube	

Note: Pin Assignment: G: Gate D: Drain S: Source



MARKING





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■ **ABSOLUTE MAXIMUM RATINGS** (T_C=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V_{DSS}	500	V
Gate-Source Voltage		V_{GSS}	±30	V
Drain Current	Continuous	I_{D}	14	Α
	Pulsed (Note 2)	I _{DM}	56	Α
Avalanche Energy	Single Pulsed (Note 3)	E _{AS}	933	mJ
Peak Diode Recovery dv/dt		dv/dt	2.6	V/ns
Power Dissipation		P_D	58	W
Junction Temperature		TJ	+150	°C
Storage Temperature		T _{STG}	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

- 2. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 3. L =144mH, I_{AS} = 3.6A, V_{DD} = 50V, R_{G} = 25 Ω , Starting T_{J} = 25 $^{\circ}$ C
- 4. $I_{SD} \le 14A$, di/dt $\le 200A/\mu s$, $V_{DD} \le BV_{DSS}$, Starting $T_J = 25^{\circ}C$

■ THERMAL DATA

PARAMETER	SYMBOL	RATING	UNIT	
Junction to Ambient	θ_{JA}	62.5	°C/W	
Junction to Case	θ _{JC}	2.15	°C/W	

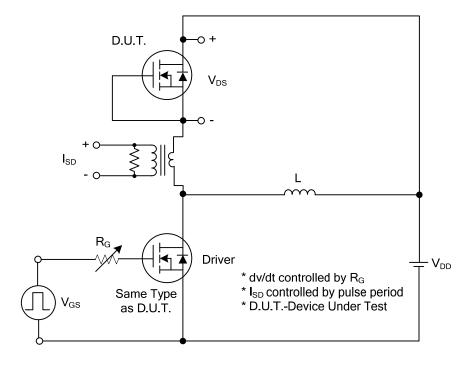
■ ELECTRICAL CHARACTERISTICS (T_C=25°C, unless otherwise specified)

PARAMETER		SYMBOL	TEST CONDITIONS		TYP	MAX	UNIT
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage		BV_{DSS}	I _D =250μA, V _{GS} =0V	500			V
Drain-Source Leakage Current		I _{DSS}	V _{DS} =500V, V _{GS} =0V				μΑ
Gate- Source Leakage Current	Forward		V _{GS} =+30V, V _{DS} =0V			+100	nA
	Reverse	I_{GSS}	V_{GS} =-30V, V_{DS} =0V			-100	nA
ON CHARACTERISTICS							
Gate Threshold Voltage		$V_{GS(TH)}$	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	2.0		4.0	V
Static Drain-Source On-State Resistance		R _{DS(ON)}	V _{GS} =10V, I _D =7.0A			0.4	Ω
DYNAMIC PARAMETERS							
Input Capacitance		C _{ISS}			1460		pF
Output Capacitance		Coss	V_{GS} =0V, V_{DS} =25V, f=1.0MHz		198		pF
Reverse Transfer Capacitance		C_{RSS}			9		pF
SWITCHING PARAMETERS							
Total Gate Charge (Note 1)		Q_G	V _{DS} =50V, V _{GS} =10V, I _D =1.3A		50		nC
Gate to Source Charge		Q_GS	I_{G} = 100µA (Note1, 2)		9		nC
Gate to Drain Charge		Q_GD	IG- 100μΑ (Note1, 2)		14		nC
Turn-ON Delay Time (Note 1)		$t_{D(ON)}$			96		ns
Rise Time		t_R	V_{DS} =30V, V_{GS} =10V, I_{D} =0.5A,		124		ns
Turn-OFF Delay Time		$t_{D(OFF)}$	R _G =25Ω (Note1, 2)		290		ns
Fall-Time		t_{F}			94		ns
SOURCE- DRAIN DIODE RATIN	IGS AND CH	ARACTERIS [*]	TICS				
Maximum Body-Diode Continuous Current		I _S				14	Α
Maximum Body-Diode Pulsed Current		I _{SM}				56	Α
Drain-Source Diode Forward Voltage (Note 1)		V_{SD}	I _S =7.0A, V _{GS} =0V			1.4	V
Body Diode Reverse Recovery Time (Note 1)		t _{RR}	I _S =14A, V _{GS} =0V,		380		ns
Reverse Recovery Charge		Q_{RR}	dI _F /dt=100A/μs (Note 1)		5.5		μC

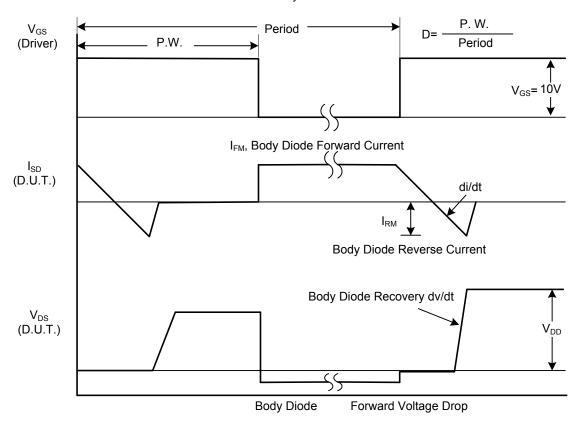
Notes: 1. Pulse Test: Pulse width ≤ 300µs, Duty cycle ≤ 2%.

2. Essentially independent of operating temperature.

■ TEST CIRCUITS AND WAVEFORMS

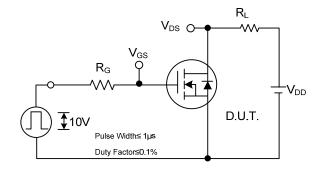


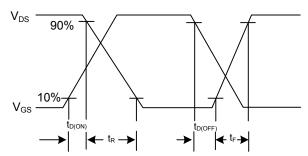
Peak Diode Recovery dv/dt Test Circuit



Peak Diode Recovery dv/dt Waveforms

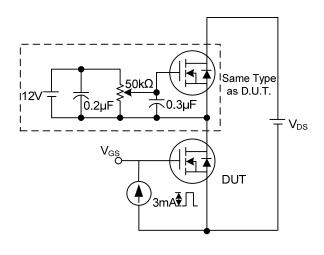
■ TEST CIRCUITS AND WAVEFORMS (Cont.)

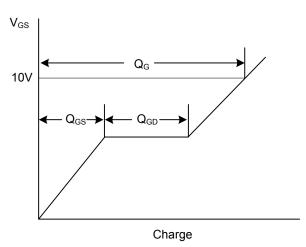




Switching Test Circuit

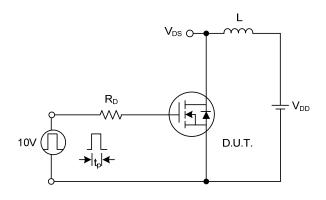
Switching Waveforms

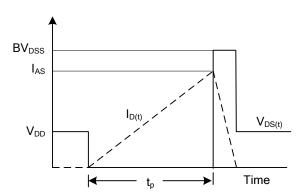




Gate Charge Test Circuit

Gate Charge Waveform





Unclamped Inductive Switching Test Circuit

Unclamped Inductive Switching Waveforms

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